Syntheses, Crystal and electronic Structures, and

Characterizations of Quaternary Antiferromagnetic

Sulfides: Ba₂MFeS₅ (M= Sb, Bi)

Lei Geng, ab Wen-Dan Cheng, a Hao Zhang, Chen-Sheng Lin, Wei-Long Zhang, Ye-Yu Li, ab and Zhang-Zhen He

E-mail: cwd@fjirsm.ac.cn

Supporting Information

Table S1. The definitions and related state energies (eV) of the special k points for Ba₂SbFeS₅ crystal.

k point	H-VB ^a	L-CB ^b
$\Gamma(0.0, 0.0, 0.0)$	-0.00641	1.00872
F(0.0, 0.5, 0.0)	-0.0804	1.01268
Q(0.0, 0.5, 0.5)	-0.10628	1.00526
Z(0.0, 0.0, 0.5)	-0.05219	0.99074
X(0.5, 0.0, 0.5)	-0.01906	1.1073

^aH-VB, the highest valence band; ^bL-CB, the lowest conduction band.

^a State Key Laboratory of Structural Chemistry, Fujian Institute of Research on the Structure of Matter, Chinese Academy of Sciences, Fuzhou 350002, P. R. China

^b Graduate School of the Chinese Academy of Sciences, Beijing, 100039, P. R. China

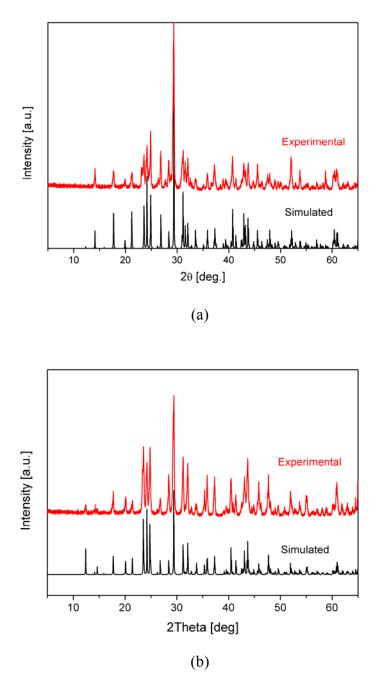


Figure S1. Experimented and simulated X-ray diffraction patterns for polycrystalline Ba_2SbFeS_5 (a) and Ba_2BiFeS_5 (b). (The radiation wavelength of the X-ray is $\lambda = 1.5418$ Å.)

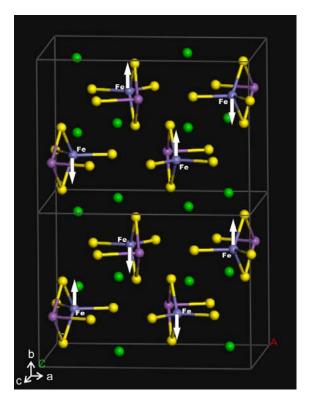


Figure S2. The spin polarization configurations adopted in the band structure calculations for compound Ba₂BiFeS₅.

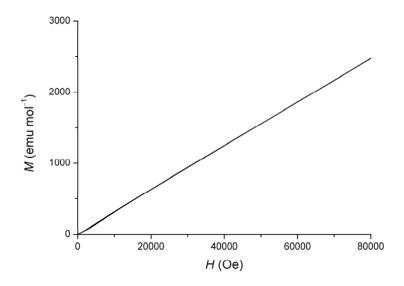


Figure 3. Magnetization (*M*) as a function of magnetic field (*H*) for compound Ba_2BiFeS_5 at T = 2 K.